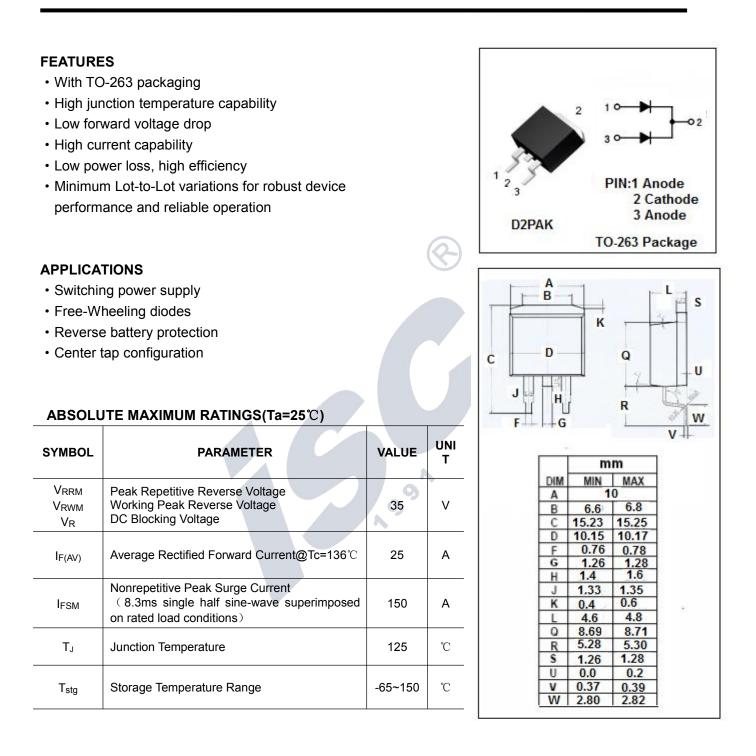


### INCHANGE SEMICONDUCTOR

## Schottky Barrier Rectifier

# MBRB2535CTL



# **Schottky Barrier Rectifier**

## MBRB2535CTL

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	2.0	°C <b>/W</b>

#### ELECTRICAL CHARACTERISTICS (Pulse Test: Pulse Width=300 µ s,Duty Cycle≤1%)

SYMBOL	PARAMETER	CONDITIONS	МАХ	UNIT
VF	Maximum Instantaneous Forward Voltage	I⊧= 12.5A ; Tc= 25℃	0.47	V
		I <sub>F</sub> = 12.5A ; Tc= 125 ℃	0.41	
		I <sub>F</sub> = 25A ; Tc= 25℃	0.55	
IR	Maximum Instantaneous Reverse Current	V <sub>R</sub> = V <sub>RWM;</sub> Tc= 25 °C	0.5	mA
		V <sub>R</sub> = V <sub>RWM;</sub> Tc= 125℃	10	

#### NOTICE:

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